Diode Semiconductor Device - Page 1 of 1



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Inclosure Material: Plastic **Overall Length:** 0.250 inches **Overall Height:** 0.055 inches **Overall Width:** Between 0.092 inches and 0.104 inches **Mounting Facility Quantity:** 2 **Mounting Method:** Terminal **Features Provided:** Electrostatic sensitive **Semiconductor Material:** Silicon alloy Voltage Rating In Volts Per Characteristic: 30.0 working peak reverse voltage, peak total value **Current Rating Per Characteristic:** 10.00 microamperes forward current, average peak **Power Rating Per Characteristic:** 400.0 milliwatts small-signal input power, common-collector preset **Nuclear Hardness Critical Feature:** Hardened **Terminal Type And Quantity:** 2 uninsulated wire lead **Specification Data:** 07187-8521485 manufacturers source control Shelf Life: N/a Unit Of Measure: --**Demilitarization:** No Fiig: A110a0